Single-Output LDO Regulator

1A Fixed Output LDO Regulators

BD80C0AFPS BD90C0AFPS

●General Description

The BD80C0AFPS and BD90C0AFPS are low-saturation regulators. These ICs have built in over current protection to protect the device when output is shorted and thermal shutdown circuit to protect the device during over load conditions.

●Features

- Output Current capability : 1A
- High Output Voltage Precision: ±1%
- Low saturation with PDMOS output
- Built-in over-current protection circuit that prevents the destruction of the IC due to output short circuits
- Built-in thermal shutdown circuit for protecting the IC from thermal damage due to overloading
- Low ESR Capacitor

●Applications

Audiovisual equipments, FPDs, televisions, personal computers or any other consumer device

●Key Specification

- Supply Voltage range: Vo+1.0V to 26.5V
- Output voltage
  - BD80C0AFPS: 8.0V
  - BD90C0AFPS: 9.0V
- Output current: 1A
- Operating temperature range: -40℃≤Ta≤+105℃

●Package

	W (Typ.) x D (Typ.) x H (Max.)
TO252S-3	6.50mm x 9.50mm x 1.30mm



TO252S-3

●Typical Application Circuit

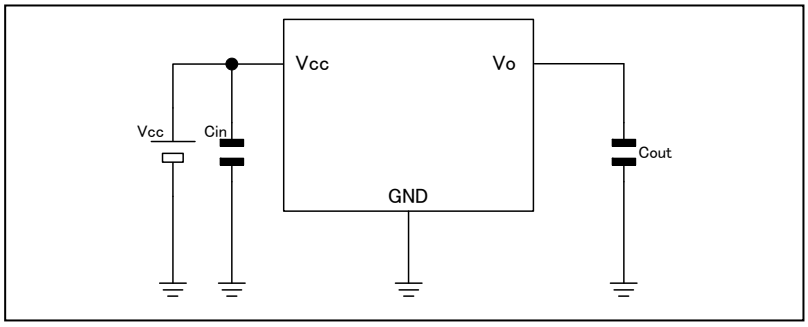


Figure 1. Typical Application Circuit

●Ordering Information

B D x x C 0 A F P S - E 2

Part Number	Output Voltage	Current capacity	Package	Packaging and forming specification
	80:8.0V Output 90:9.0V Output	C0A:1A	FPS:TO252S-3	E2: Embossed tape and reel

●Lineup

Maximum Output Current (Max.)	Output Voltage (Typ.)	Package		Orderable Part Number
1A	8.0V	TO252S-3	Reel of 2000	BD80C0AFPS -E2
	9.0V			BD90C0AFPS -E2

○Product structure：Silicon monolithic integrated circuit ○This product is not designed protection against radioactive rays.

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●Pin Configuration

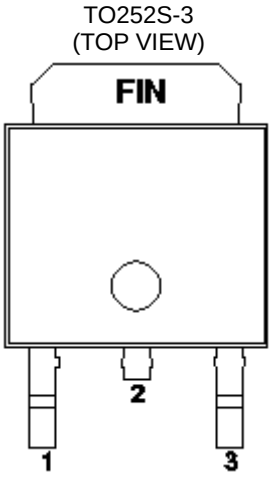


Figure 2. Pin Configuration

●Pin Description

Pin No.	Symbol	Function
1	Vcc	Power Supply Pin
2	N.C.	N.C. Pin
3	Vo	Output Pin
FIN	GND	GND

※N.C.Pin can be open. Because it isn't connect it inside of IC.

●Block Diagram

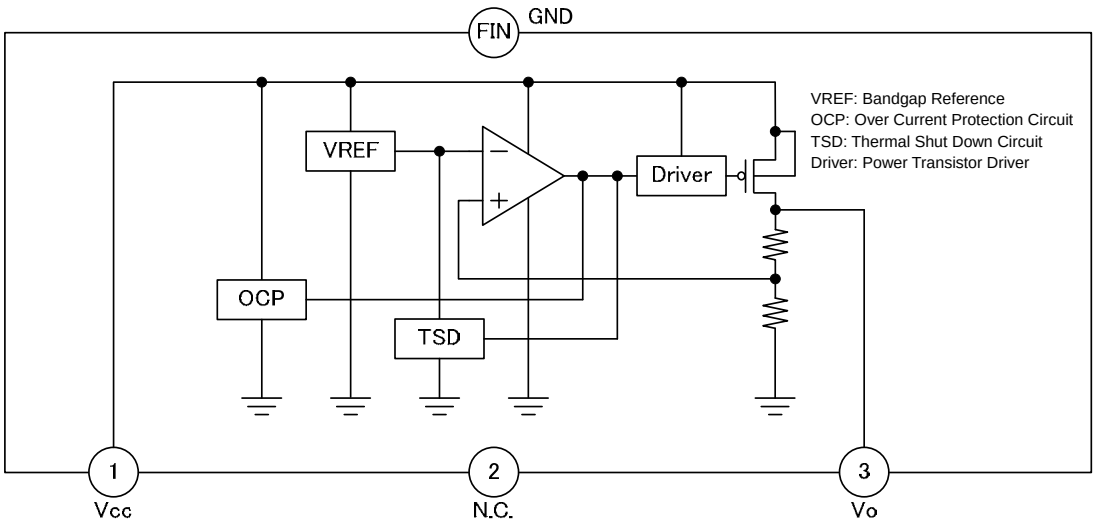


Figure 3. Block Diagram

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●Absolute Maximum Ratings (Ta=25℃)

Parameter	Symbol	Ratings	Unit
Supply Voltage *1	V_{CC}	-0.3 to +35.0	V
Power Dissipation *2	Pd	1.2	W
Operating Temperature Range	Topr	-40 to +105	℃
Storage Temperature Range	Tstg	-55 to +150	℃
Maximum Junction Temperature	Tjmax	+150	℃

*1 Not to exceed Pd.
*2 TO252S-3:Reduced by 9.6mW / °C over Ta = 25°C, when mounted on glass epoxy board: 70mm × 70mm × 1.6mm.

●Recommended Operating Ratings (Ta=25℃)

■BD80C0AFPS

Parameter	Symbol	Min.	Max.	Unit
Supply Voltage	V_{CC}	9.0	26.5	V
Output Current	Io	0	1.0	A

■BD90C0AFPS

Parameter	Symbol	Min.	Max.	Unit
Supply Voltage	Vcc	10.0	26.5	V
Output Current	Io	0	1.0	A

●Electrical Characteristics

■BD80C0AFPS (Unless otherwise specified, Ta=25℃, Vcc=13V, Io=0mA)

Parameter	Symbol	Guaranteed Limits			Unit	Conditions
		Min.	Typ.	Max.		
Circuit Current	Ib	−	0.6	1.0	mA	
Output Voltage	Vo	7.92	8.00	8.08	V	Io=500mA
Dropout Voltage	ΔVd	−	0.3	0.5	V	V_{CC}=Vo × 0.95, Io=500mA
Ripple Rejection	R.R.	40	50	−	dB	f=120Hz,ein*1=1Vrms, Io=100mA
Line Regulation	Reg.I	−	20	60	mV	V_{CC}=9→25V
Load Regulation	Reg.L	−	Vo×0.010	Vo×0.015	V	Io=5mA→1A
Temperature Coefficient of Output Voltage	Tcvo.1	−	+0.04	−	%/℃	Io=5mA,Tj=-40℃ to -20℃
	Tcvo.2	−	±0.005	−	%/℃	Io=5mA,Tj=-20℃ to +105℃

*1 ein: Input Voltage Ripple

■BD90C0AFPS (Unless otherwise specified, Ta=25℃, Vcc=14V, Io=0mA)

Parameter	Symbol	Guaranteed Limits			Unit	Conditions
		Min.	Typ.	Max.		
Circuit Current	Ib	−	0.6	1.0	mA	
Output Voltage	Vo	8.91	9.00	9.09	V	Io=500mA
Dropout Voltage	ΔVd	−	0.3	0.5	V	V_{CC}=Vo × 0.95, Io=500mA
Ripple Rejection	R.R.	40	50	−	dB	f=120Hz,ein*1=1Vrms, Io=100mA
Line Regulation	Reg.I	−	20	60	mV	V_{CC}=10→25V
Load Regulation	Reg.L	−	Vo×0.010	Vo×0.015	V	Io=5mA→1A
Temperature Coefficient of Output Voltage	Tcvo.1	−	+0.04	−	%/℃	Io=5mA,Tj=-40℃ to -20℃
	Tcvo.2	−	±0.005	−	%/℃	Io=5mA,Tj=-20℃ to +105℃

*1 ein: Input Voltage Ripple

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●**Typical Performance Curves**

BD80C0AFPS (Unless otherwise specified, Ta=25℃, Vcc=13V, Io=0mA)

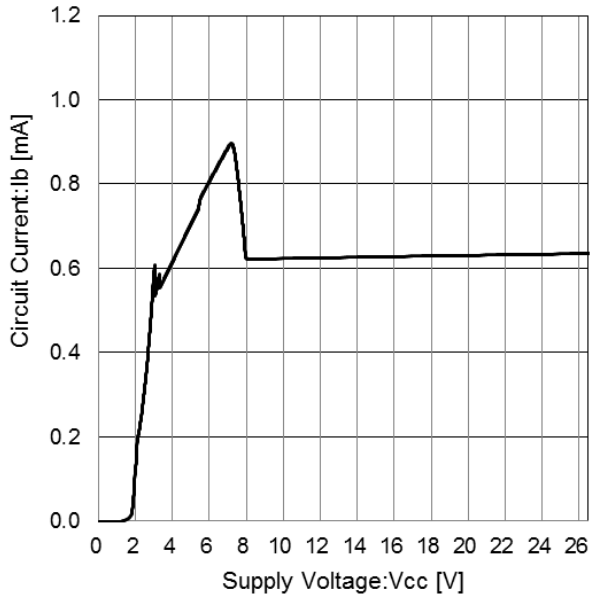


Figure 4. Circuit Current

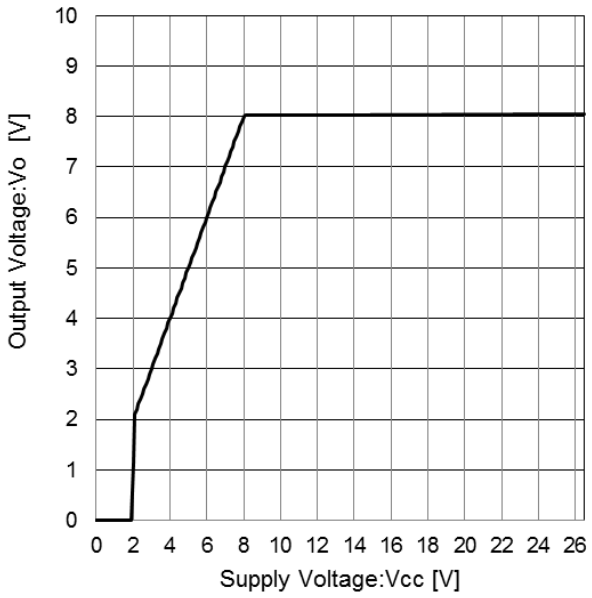


Figure 5. Line Regulation
(Io=0mA)

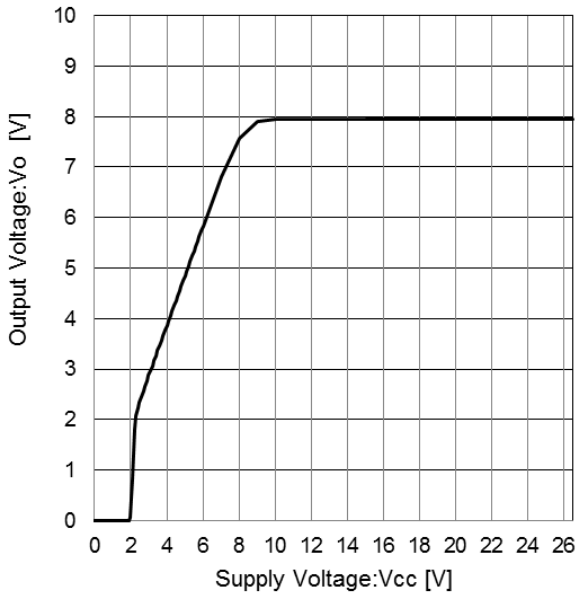


Figure 6. Line Regulation
(Io=500mA)

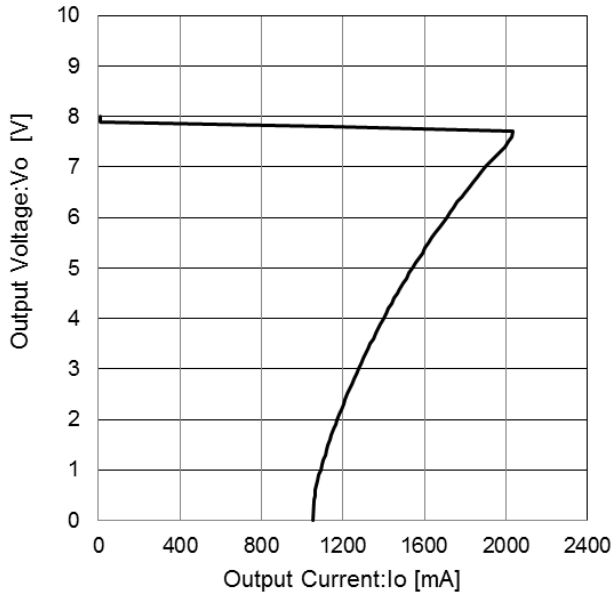


Figure 7. Load Regulation

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●**Typical Performance Curves - Continued**

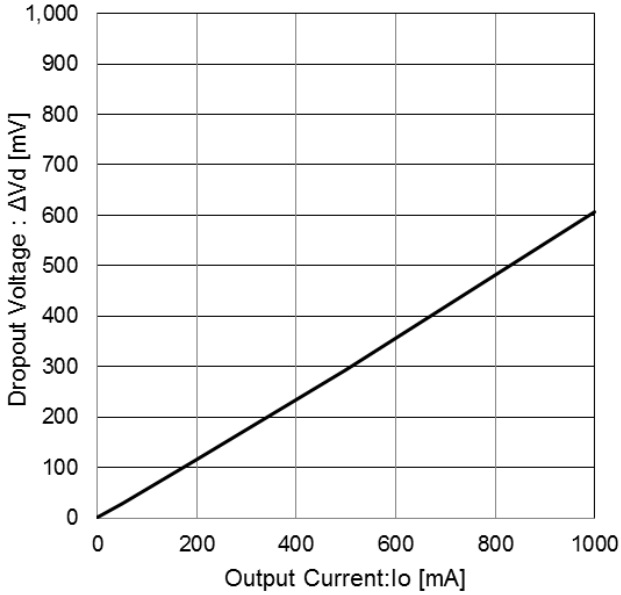


Figure 8. Dropout Voltage
(Vcc=Vo×0.95V)
(Io=0mA→1000mA)

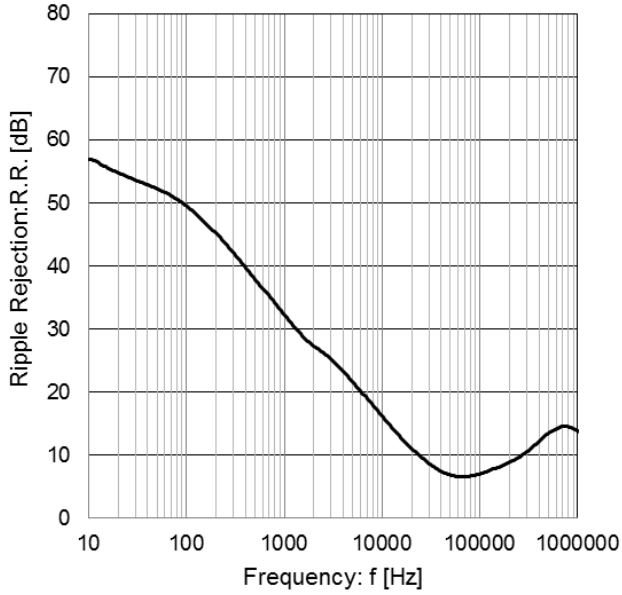


Figure 9. Ripple Rejection
(Io =100mA)

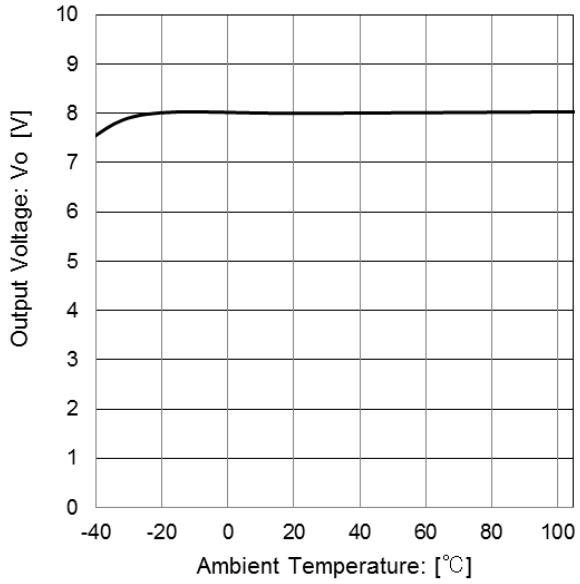


Figure 10. Output Voltage
Temperature Characteristic

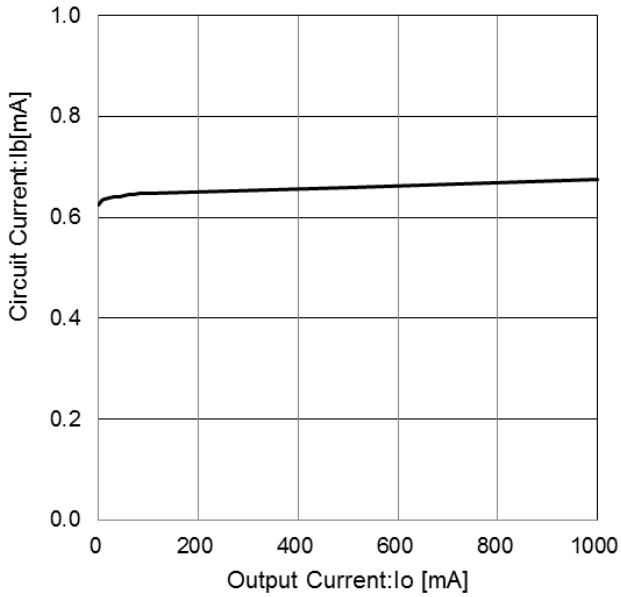


Figure 11. Circuit Current
(Io=0mA→1000 mA)

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●**Typical Performance Curves - Continued**

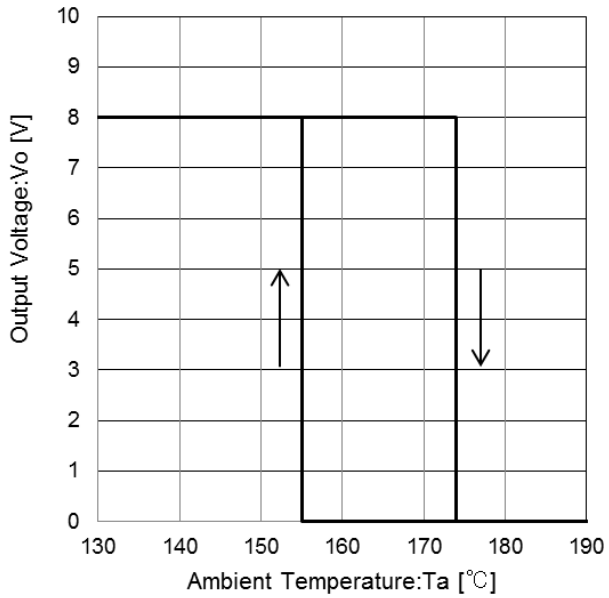


Figure 12. Thermal Shutdown Circuit Characteristic

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●**Typical Performance Curves - Continued**

BD90C0AFPS (Unless otherwise specified, Ta=25℃, Vcc=14V, Io=0mA)

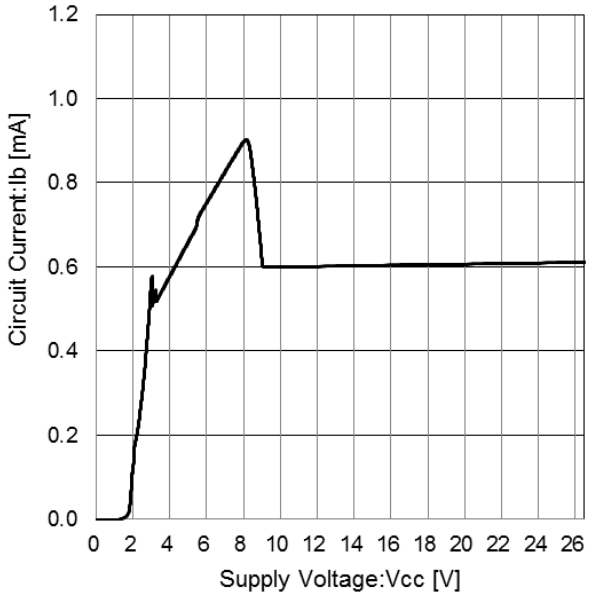


Figure 13. Circuit Current

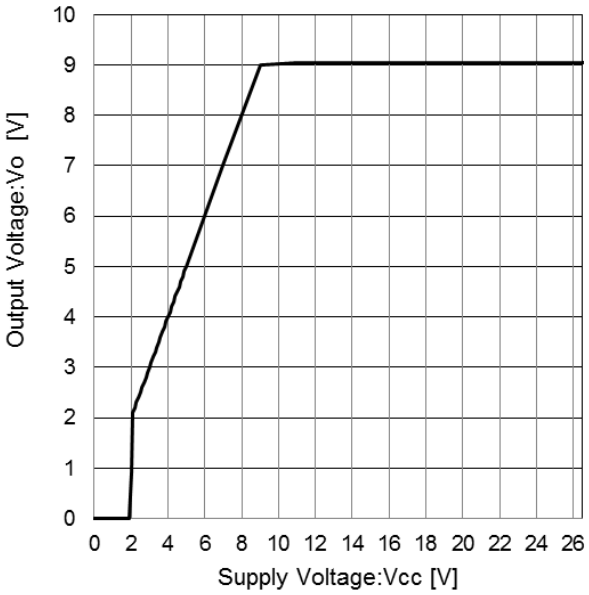


Figure 14. Line Regulation
(Io=0mA)

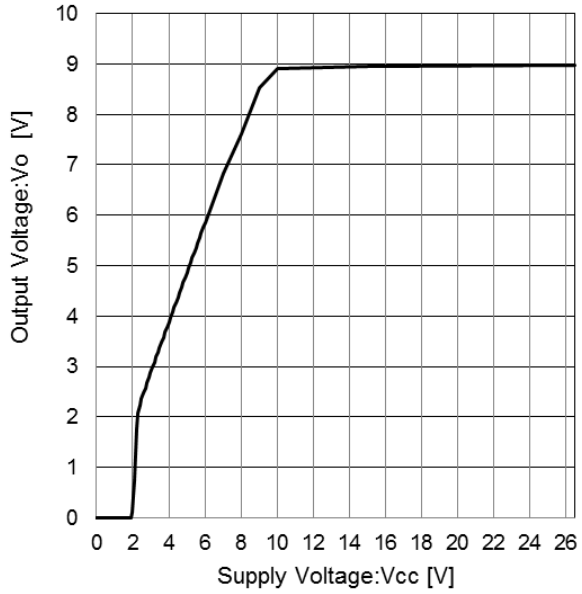


Figure 15. Line Regulation
(Io=500mA)

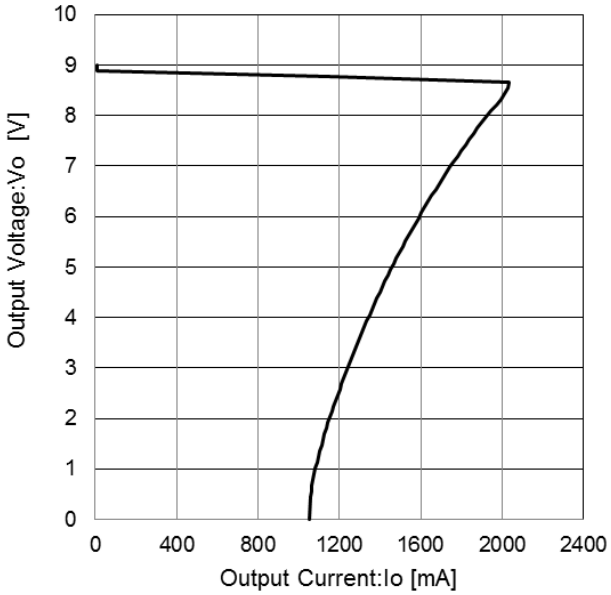


Figure 16. Load Regulation

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●**Typical Performance Curves - Continued**

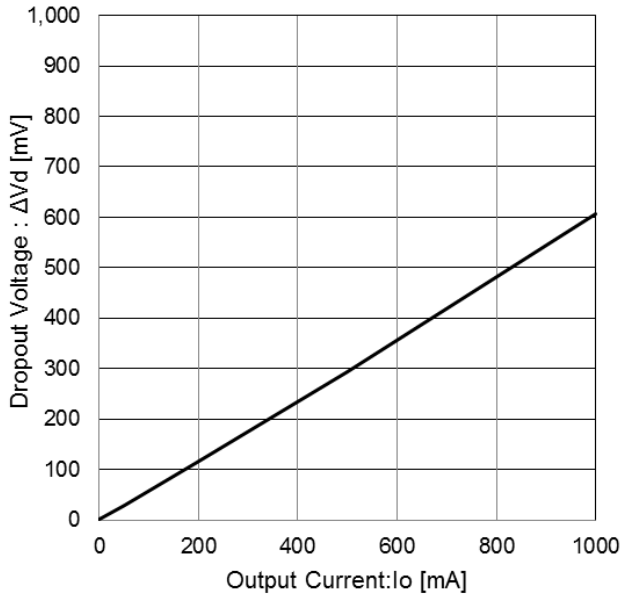


Figure 17. Dropout Voltage
(Vcc=Vo×0.95V)
(Io=0mA→1000mA)

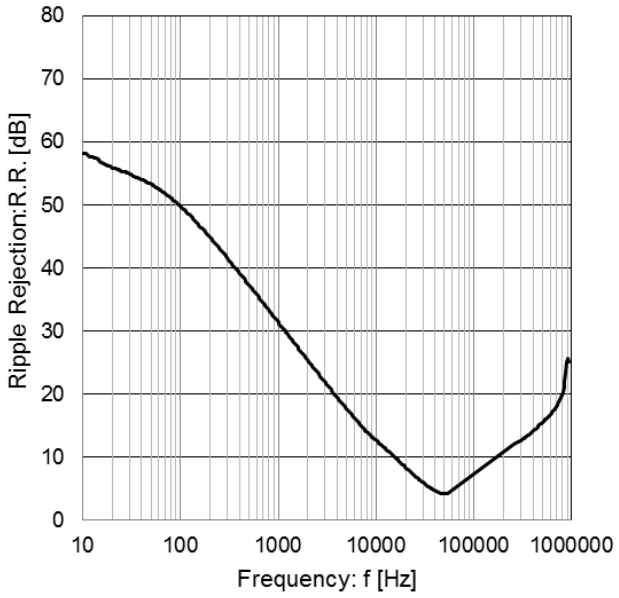


Figure 18. Ripple Rejection
(Io=100mA)

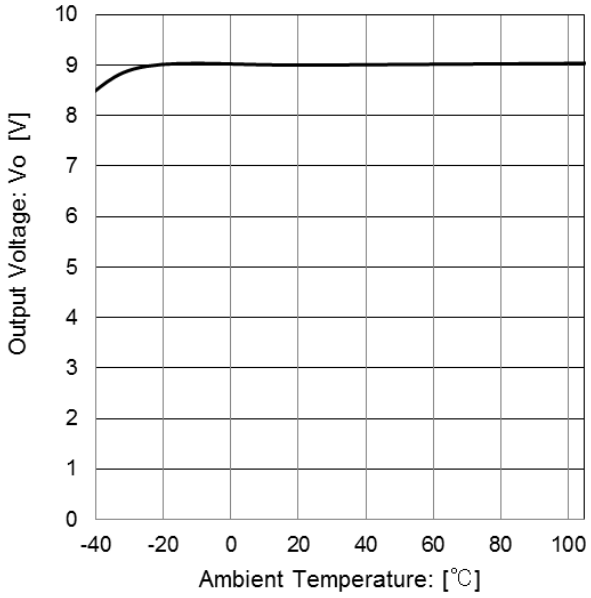


Figure 19. Output Voltage
Temperature Characteristic

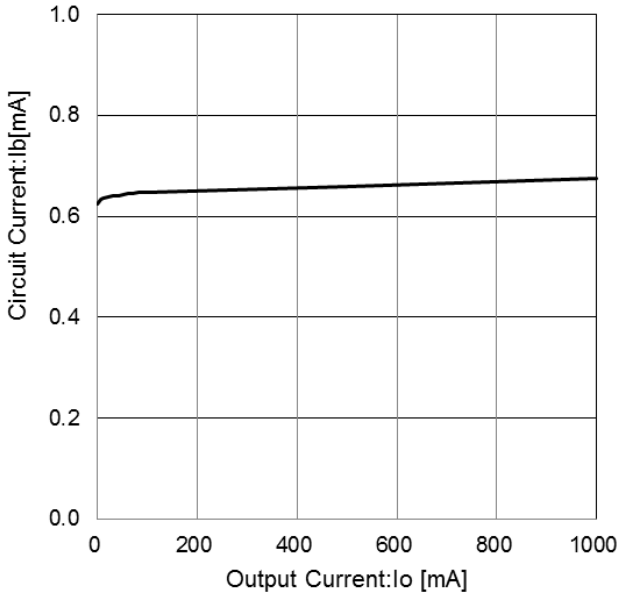


Figure 20. Circuit Current
(Io=0mA→1000 mA)

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●**Typical Performance Curves - Continued**

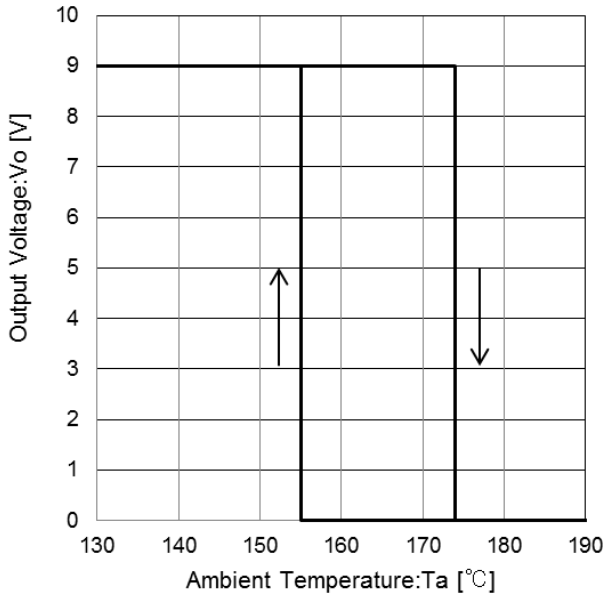
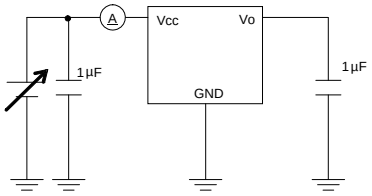


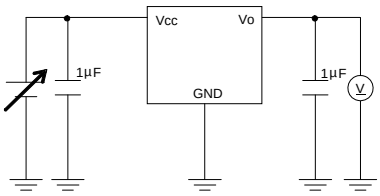
Figure 21. Thermal Shutdown Circuit Characteristic

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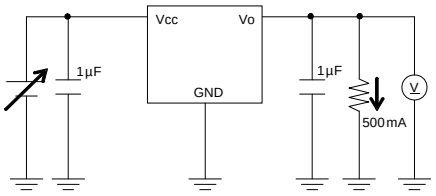
●Measurement Circuit for Typical Performance Curves (BD80C0AFPS and BD90C0AFPS)



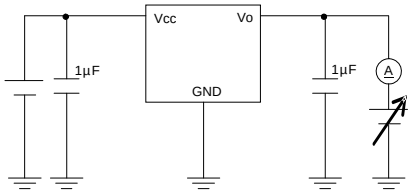
Measurement Circuit of
Figure 4 and Figure 13



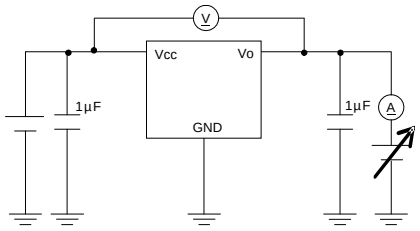
Measurement Circuit of
Figure 5 and Figure 14



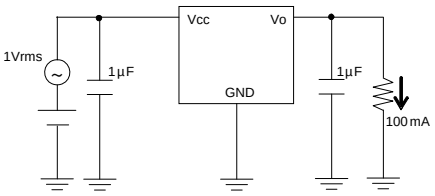
Measurement Circuit of
Figure 6 and Figure 15



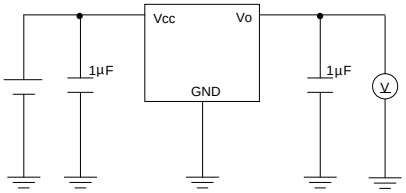
Measurement Circuit of
Figure 7 and Figure 16



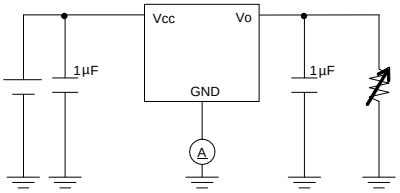
Measurement Circuit of
Figure 8 and Figure 17



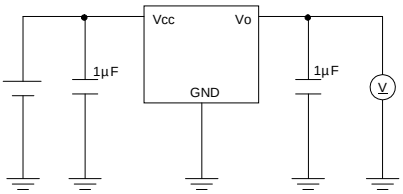
Measurement Circuit of
Figure 9 and Figure 18



Measurement Circuit of
Figure 10 and Figure 19



Measurement Circuit of
Figure 11 and Figure 20



Measurement Circuit of
Figure 12 and Figure 21

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●Application Examples

・Positive voltage surges on V_{CC} pin

A power zener diode should be inserted between V_{CC} and GND for protection against voltage surges of more than 35V on the V_{CC} pin.

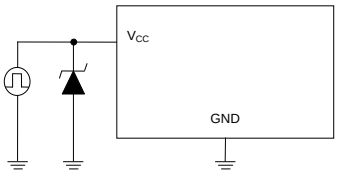


Figure 22.

・Negative voltage surges on V_{CC} pin

A schottky barrier diode should be inserted between V_{CC} and GND for protection against voltages lower than GND on the V_{CC} pin.

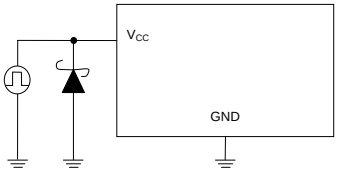


Figure 23.

・Output protection diode

Loads with large inductance components may cause reverse current flow during startup or shutdown. In such cases, a protection diode should be inserted on the output to protect the IC.

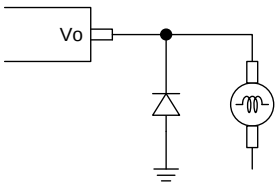


Figure 24.

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●**Power Dissipation**

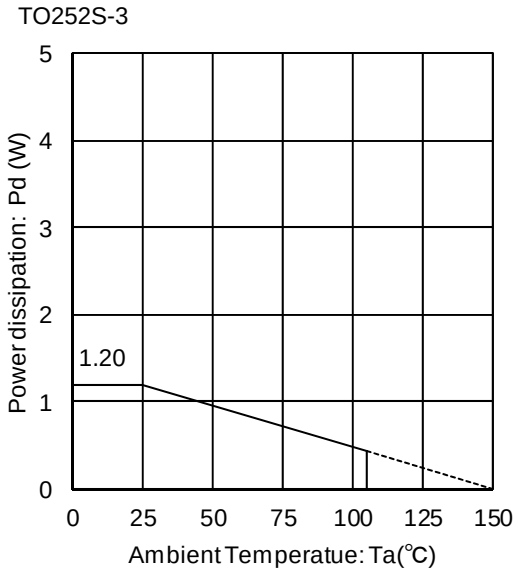


Figure 25.

Mounted on a Rohm standard board
Board size : 70mm × 70 mm × 1.6 mm
Copper foil area :7mm × 7mm

TO252S-3 θja=104.2(℃/W)

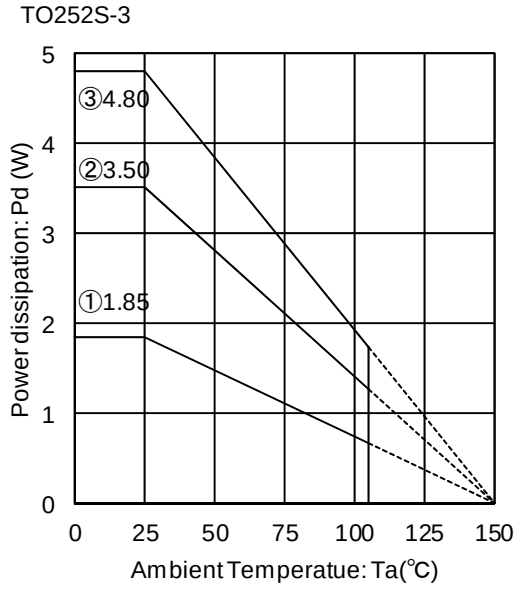


Figure 26.

IC mounted on a ROHM standard board
Board size : 70mm×70mm×1.6mm
Copper area : 7mm×7mm

①:2-layer PCB
(Copper foil area on the reverse side of PCB:15mm×15mm)
②:2-layer PCB
(Copper foil area on the reverse side of PCB:70mm×70mm)
③:4-layer PCB
(Copper foil on the reverse side of PCB:70mm×70mm)

①:θja=67.6℃/W
②:θja=35.7℃/W
③:θja=26.0℃/W

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When used at temperatures over Ta=25℃, please refer to the power dissipation curve shown in Figure 25 and Figure 26. The IC characteristics are closely related to the temperature at which the IC is used, so it is necessary to operate the IC at temperatures less than the maximum junction temperature Tjmax.

Figure 25 and Figure 26 show the acceptable power dissipation curve of the TO252S-3 package. Even when the ambient temperature Ta is at normal temperature (25℃), the chip (junction) temperature Tj may be quite high, so please operate the IC at temperature less than the acceptable power dissipation Pd.

The calculation method for power consumption Pc(W) is as follows :(Figure 26③)

$Pc = (Vcc - Vo) \times Io + Vcc \times Ib$

Acceptable loss $Pd \geq Pc$

Vcc: Input voltage
Vo: Output voltage
Io: Load current
Ib: Circuit current
Ishort: Short current

Solving this for load current Io in order to operate within the acceptable power dissipation,

$$Io \leq \frac{Pd - Vcc \times Ib}{Vcc - Vo}$$

(Please refer to Figure 11, Figure 20 for Ib.)

It is then possible to find the maximum load current Io_{Max} with respect to the applied voltage Vcc at the time of thermal design.

Calculation Example for BD80C0AFPS)

When Ta=85℃, Vcc=13V, Vo=8V

$$Io \leq \frac{2.496 - 13 \times Ib}{5}$$

(Figure 26③ :θja=26.0℃/W → -38.4mW/℃
25℃=4.80W → 85℃=2.496W)

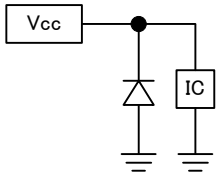
$Io \leq 497.6mA$ (Ib: 0.6 mA)

Please refer to the above information and keep thermal designs within the scope of acceptable loss for all operating temperature ranges. The power consumption Pc of the IC when there is a short circuit (short between Vo and GND) is :

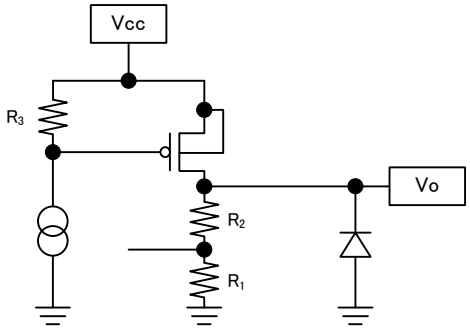
$Pc = Vcc \times (Ib + Ishort)$ (Please refer to Figure 7,Figure 16 for Ishort.)

●Input / Output Equivalent Circuit Diagrams

Vcc terminal



Vo terminal



	R_1 (kΩ)	R_2 (kΩ)	R_3 (kΩ)
BD80C0AFPS	5	48.3	20
BD90C0AFPS		55	

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●Operational Notes

1. Absolute maximum ratings
   Exceeding the absolute maximum rating for supply voltage, operating temperature or other parameters can result in damages to or destruction of the chip. In this event it also becomes impossible to determine the cause of the damage (e.g. short circuit, open circuit, etc). Therefore, if any special mode is being considered with values expected to exceed the absolute maximum ratings, implementing physical safety measures, such as adding fuses, should be considered.

2. The electrical characteristics given in this specification may be influenced by conditions such as temperature, supply voltage and external components. Transient characteristics should be sufficiently verified..

3. GND electric potential
   Keep the GND pin potential at the lowest (minimum) level under any operating condition. Furthermore, ensure that, including the transient, none of the pin's voltages are less than the GND pin voltage.

4. Ground wiring pattern
   When both a small-signal GND and a high current GND are present, single-point grounding (at the set standard point) is recommended. This in order to separate the small-signal and high current patterns and to ensure that voltage changes stemming from the wiring resistance and high current do not cause any voltage change in the small-signal GND. Similarly, care must be taken to avoid wiring pattern fluctuations in any connected external component GND.

5. Inter-pin shorting and mounting errors
   Ensure that when mounting the IC on the PCB the direction and position are correct. Incorrect mounting may result in damaging the IC. Also, shorts caused by dust entering between the output, input and GND pin may result in damaging the IC.

6. Operation Under Strong Electromagnetic Field
   Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

7. Inspection using the set board
   The IC needs to be discharged after each inspection process as, while using the set board for inspection, connecting a capacitor to a low-impedance pin may cause stress to the IC. As a protection from static electricity, ensure that the assembly setup is grounded and take sufficient caution with transportation and storage. Also, make sure to turn off the power supply when connecting and disconnecting the inspection equipment.

8. Power dissipation (Pd)
   Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. The absolute maximum rating of the Pd stated in this specification is when the IC is mounted on a 70mm X 70mm X 1.6mm glass epoxy board. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

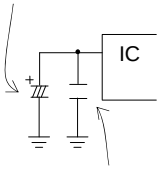
9. Thermal design
   The power dissipation under actual operating conditions should be taken into consideration and a sufficient margin should be allowed for in the thermal design. On the reverse side of the package this product has an exposed heat pad for improving the heat dissipation. Use both the front and reverse side of the PCB to increase the heat dissipation pattern as far as possible. The amount of heat generated depends on the voltage difference across the input and output, load current, and bias current. Therefore, when actually using the chip, ensure that the generated heat does not exceed the Pd rating.

   (Tjmax: Maximum junction temperature=150[℃], Ta: Peripheral temperature [℃],
   θja : Thermal resistance of package-ambience[℃/W], Pd : Package Power dissipation [W],
   Pc: Power dissipation [W], Vcc: Input Voltage, Vo: Output Voltage, Io: Load, Ib : Circuit Current)

   Package Power dissipation : $Pd\ (W) = (Tjmax-Ta) / \theta ja$
   Power dissipation : $Pc\ (W) = (Vcc-Vo) \times Io + Vcc \times Ib$

10. Vcc pin
    Insert a capacitor with a capacitance of 1μF or higher between the Vcc and GND pins. Choose the capacitance according to the line between the power smoothing circuit and the Vcc pin. Selection of the capacitance also depends on the application. Verify the application and allow for sufficient margins in the design. We recommend using a capacitor with excellent voltage and temperature characteristics.

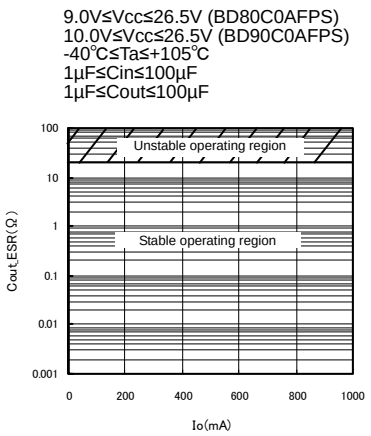
Electric capacitance



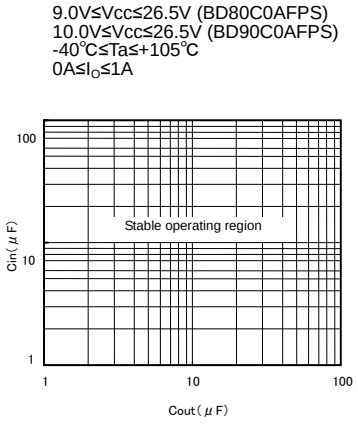
Ceramic capacitors, Low ESR capacitor

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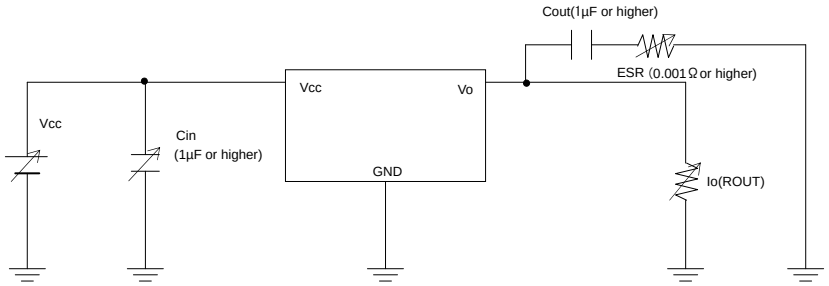
11. Output pin
In order to prevent oscillation, a capacitor needs to be placed between the output pin and GND pin. We recommend a capacitor with a capacitance of more than 1μF. Electrolytic, tantalum and ceramic capacitors can be used. When selecting the capacitor ensure that the capacitance of more than 1μF is maintained at the intended applied voltage and temperature range. Due to changes in temperature, the capacitance can fluctuate possibly resulting in oscillation. For selection of the capacitor refer to the Cout ESR vs. Io. The stable operation range given in the reference data is based on the standalone IC and resistive load. For actual applications the stable operating range is influenced by the PCB impedance, input supply impedance and load impedance. Therefore verification of the final operating environment is needed.
When selecting a ceramic type capacitor, we recommend using X5R, X7R or better with excellent temperature and DC-biasing characteristics and high voltage tolerance.
Also, in case of rapidly changing input voltage and load current, select the capacitance in accordance with verifying that the actual application meets with the required specification.



Cout_ESR vs Io(reference data)



Cin vs Cout(reference data)



※Operation Note 11 Measurement circuit

12. Rapid variation in Vcc voltage and load current
In case of a rapidly changing input voltage, transients in the output voltage might occur due to the use of a MOSFET as output transistor. Although the actual application might be the cause of the transients, the IC input voltage, output current and temperature are also possible causes. In case problems arise within the actual operating range, use countermeasures such as adjusting the output capacitance.

13. Minute variation in output voltage
In case of using an application susceptible to minute changes to the output voltage due to noise, changes in input and load current, etc., use countermeasures such as implementing filters.

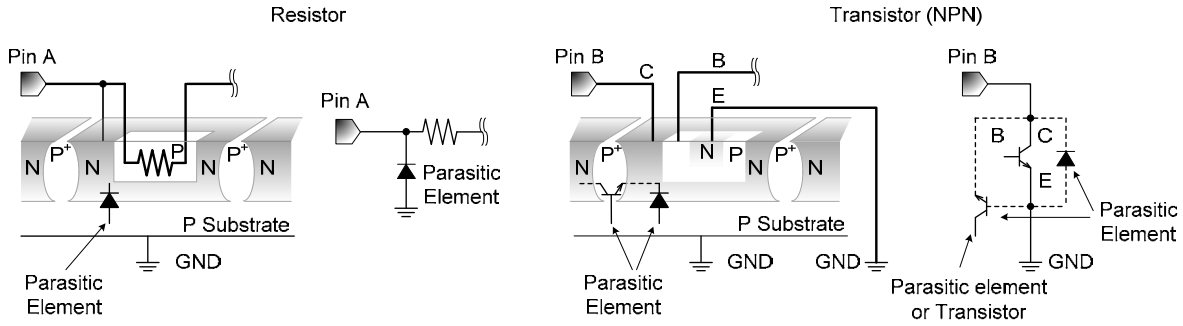
14. Over current protection circuit (OCP)
This IC incorporates an integrated overcurrent protection circuit that is activated when the load is shorted. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection circuit.

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15. Thermal shutdown circuit (TSD)
This IC incorporates and integrated thermal shutdown circuit to prevent heat damage to the IC. Normal operation should be within the power dissipation rating, if however the rating is exceeded for a continued period, the junction temperature (Tj) will rise and the TSD circuit will be activated and turn all output pins OFF. After the Tj falls below the TSD threshold the circuits are automatically restored to normal operation.
Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

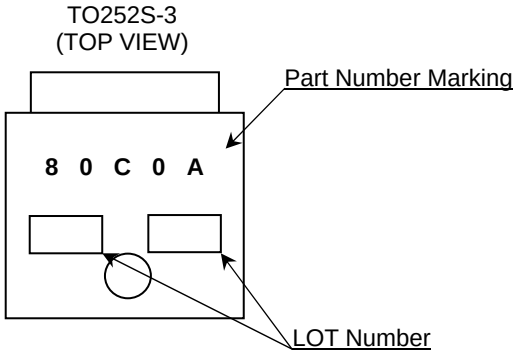
16. In some applications, the Vcc and pin potential might be reversed, possibly resulting in circuit internal damage or damage to the elements. For example, while the external capacitor is charged, the Vcc shorts to the GND. Use a capacitor with a capacitance with less than 1000μF. We also recommend using reverse polarity diodes in series or a bypass between all pins and the Vcc pin.

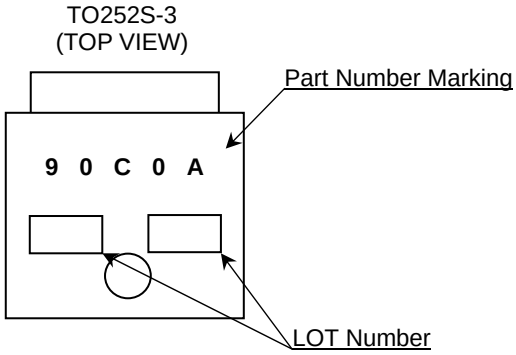
17. This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P/N junctions are formed at the intersection of these P layers with the N layers of other elements to create a variety of parasitic elements.
For example, in case a resistor and a transistor are connected to the pins as shown in the figure below then:
○ The P/N junction functions as a parasitic diode when GND > pin A for the resistor, or GND > pin B for the transistor.
○ Also, when GND > pin B for the transistor (NPN), the parasitic diode described above combines with the N layer of the other adjacent elements to operate as a parasitic NPN transistor.
Parasitic diodes inevitably occur in the structure of the IC. Their operation can result in mutual interference between circuits and can cause malfunctions and, in turn, physical damage to or destruction of the chip. Therefore do not employ any method in which parasitic diodes can operate such as applying a voltage to an input pin that is lower than the (P substrate) GND.



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●**Marking Diagrams**

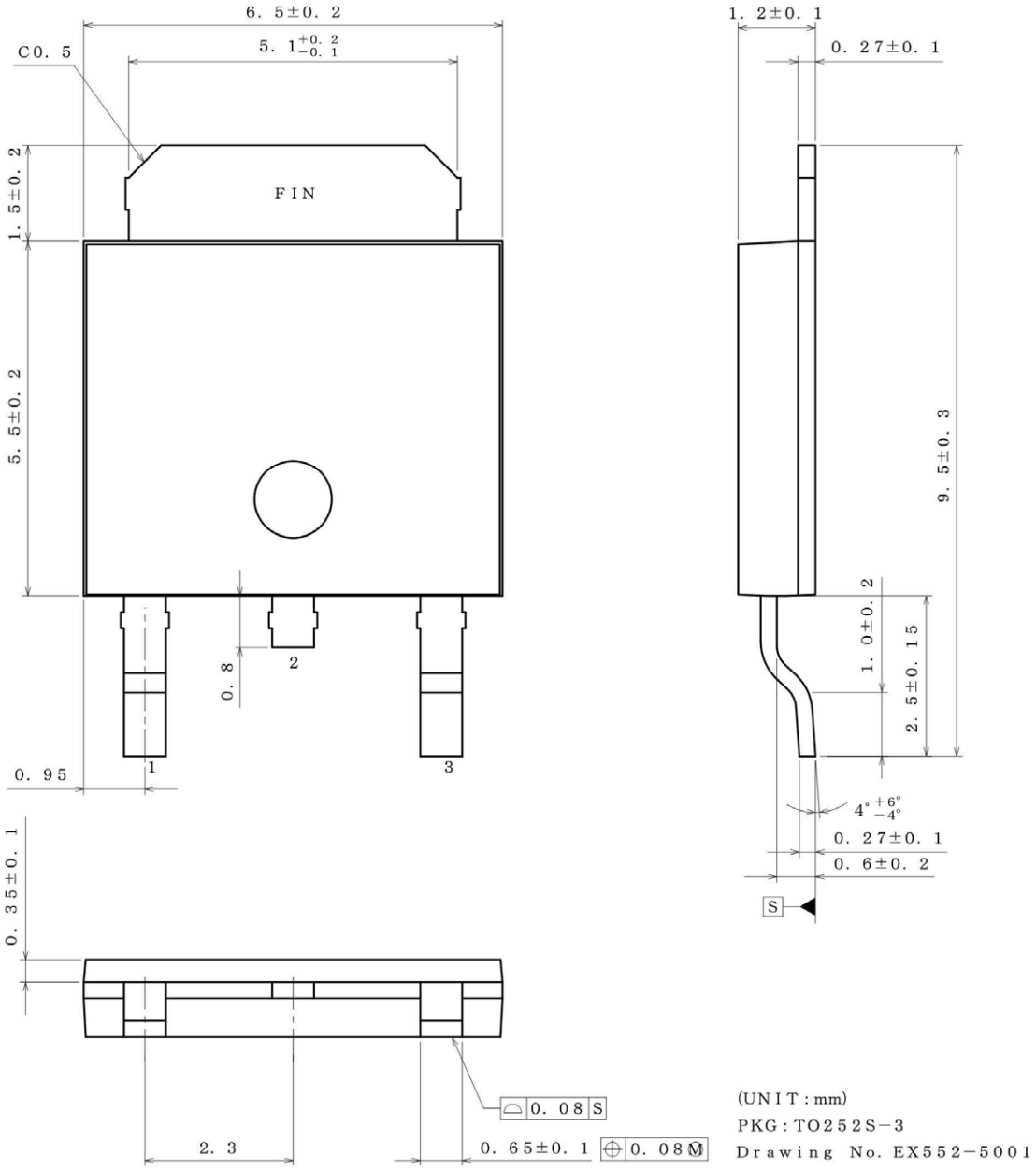




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●**Physical Dimension, Tape and Reel Information**

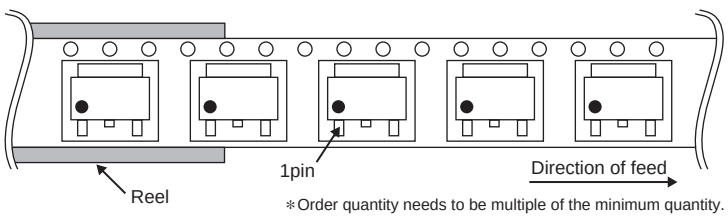
Package Name	TO252S-3



(UNIT : mm)
PKG : TO252S−3
Drawing No. EX552−5001

<Tape and Reel information>

Tape	Embossed carrier tape
Quantity	2000pcs
Direction of feed	E2 (The direction is the 1pin of product is at the lower left when you hold reel on the left hand and you pull out the tape on the right hand)



∗Order quantity needs to be multiple of the minimum quantity.

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●**Revision History**

Date	Revision	Changes
9.Apr.2014	001	New Release

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(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASSⅡb	CLASSⅢ
CLASSⅣ		CLASSⅢ	

2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
   [a] Installation of protection circuits or other protective devices to improve system safety
   [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure

3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
   [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
   [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
   [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl_2, H_2S, NH_3, SO_2, and NO_2
   [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
   [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
   [f] Sealing or coating our Products with resin or other coating materials
   [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
   [h] Use of the Products in places subject to dew condensation

4. The Products are not subject to radiation-proof design.

5. Please verify and confirm characteristics of the final or mounted products in using the Products.

6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.

7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.

8. Confirm that operation temperature is within the specified range described in the product specification.

9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.

2. In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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Precautions Regarding Application Examples and External Circuits

1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.

2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of Ionizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
   - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
   - [b] the temperature or humidity exceeds those recommended by ROHM
   - [c] the Products are exposed to direct sunshine or condensation
   - [d] the Products are exposed to high Electrostatic

2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.

3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.

4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

QR code printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

Since our Products might fall under controlled goods prescribed by the applicable foreign exchange and foreign trade act, please consult with ROHM representative in case of export.

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